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Diodes Incorporated ZUMTS17NTA

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Datasheet of ZUMTS17NTA - TRANS RF 3.2GHZ 11V SOT323

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NPN RF TRANSISTOR IN SOT323

Features

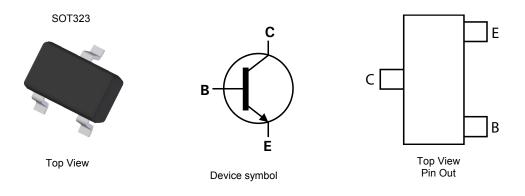
- 3.2GHz unity gain for RF switching applications
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Applications

RF Switch

Mechanical Data

- Case: SOT323
- Case Material: molded plastic, "Green" molding compound.
- UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.006 grams (approximate)



Ordering Information (Note 4)

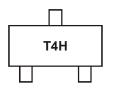
Part Number	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZUMTS17NTA	T4H	7	8	3,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen and Antimony free, "Green" and Lead-Free.

 3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl)
- and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com.

Marking Information



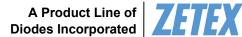
T4H = Product Type Marking Code



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Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	20	V
Collector-Emitter Voltage	V_{CEO}	11	V
Emitter-Base Voltage	V_{EBO}	3	V
Continuous Collector Current	Ic	50	mA

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Power Dissipation	(Note 5)	D-	310	mW	
Power Dissipation	(Note 6)	P_{D}	350	IIIVV	
Thermal Desistance Junation to Ambient	(Note 5)	Б	403	°C/W	
Thermal Resistance, Junction to Ambient	(Note 6)	$R_{\theta JA}$	357	30/00	
Thermal Resistance, Junction to Leads (Note 7)		R ₀ JL	350	°C/W	
Operating and Storage Temperature Range		$T_{J,}T_{STG}$	-55 to +150	°C	

ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	2,000	V	2
Electrostatic Discharge - Machine Model	ESD MM	100	V	Α

Notes:

- 5. For the device mounted on minimum recommended pad layout FR4 PCB with high coverage of single sided 1oz copper in still air condition;
- 6. Same as Note 6, expect the device is mounted on 15mm X 15mm X 1.6mm FR4 PCB
- 7. Thermal resistance from junction to solder-point (at the end of the leads). 8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

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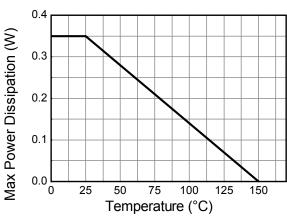
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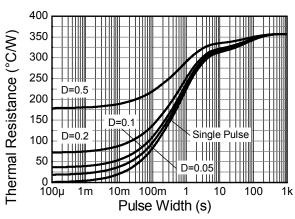




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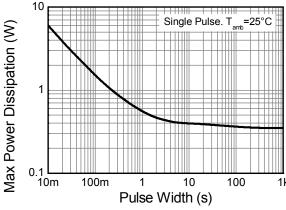
Thermal Characteristics and Derating information





Derating Curve

Transient Thermal Impedance



Pulse Power Dissipation



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Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV_{CBO}	20			٧	$I_C = 10\mu A$
Collector-Emitter Breakdown Voltage (Note 9)	BV_CEO	11		_	V	I _C = 1mA
Emitter-Base Breakdown Voltage	BV _{EBO}	3		_	V	I _E = 10μA
Collector Cutoff Current	I _{CBO}	_		0.5	μΑ	V _{CE} = 10V
Emitter Cutoff Current	I _{EBO}		_	0.5	μА	V _{EB} = 2V
Static Forward Current Transfer Ratio (Note 9)	h _{FE}	56		180	_	I _C = 5mA, V _{CE} = 10V
Collector-Emitter Saturation Voltage (Note 9)	V _{CE(SAT)}	_		0.5	V	$I_C = 10mA, I_B = 5mA$
Transition Frequency (Note 9)	f _T	1.4	3.2	_	GHz	$V_{CE} = 5V$, $I_{E} = 25mA$, $f = 500MHz$
Collector Output Capacitance (Note 9)	C_{ob}		0.8	1.5	pF	V _{CB} = 10V, f = 1.0MHz

tes: 9. Measured under pulsed conditions. Pulse width ≤ 300 μs. Duty cycle ≤ 2%

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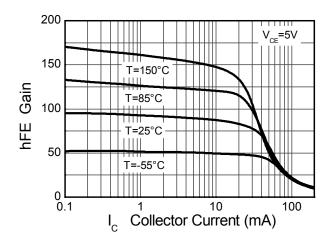
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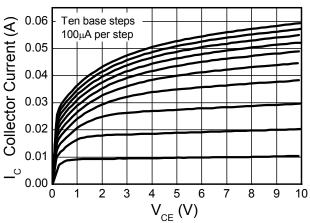


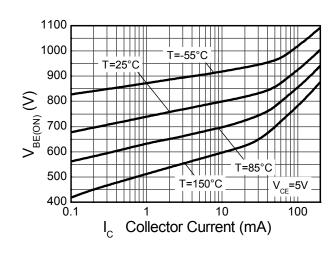


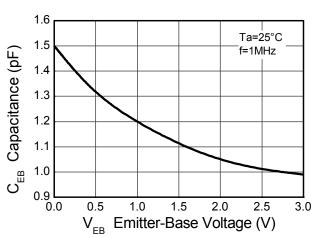
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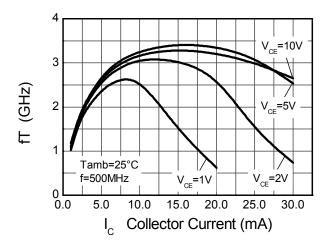
Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

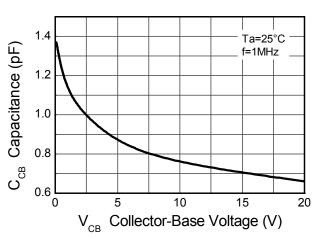












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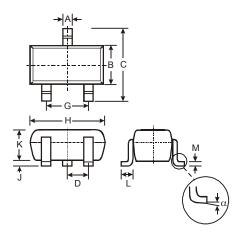




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Package Outline Dimensions

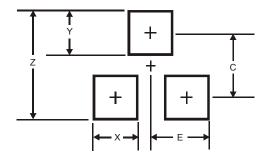
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT323					
Dim	Min	Max	Тур		
Α	0.25	0.40	0.30		
В	1.15	1.35	1.30		
C	2.00	2.20	2.10		
D	-	-	0.65		
G	1.20	1.40	1.30		
Н	1.80	2.20	2.15		
J	0.0	0.10	0.05		
K	0.90	1.00	1.00		
L	0.25	0.40	0.30		
М	0.10	0.18	0.11		
α	0°	8°	-		
All Dimensions in mm					

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)		
Z	2.8		
Х	0.7		
Υ	0.9		
С	1.9		
Е	1.0		



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